TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# TC74HCT02AP, TC74HCT02AF, TC74HCT02AFN

#### **QUAD 2-INPUT NOR GATE**

The TC74HCT02A is a high speed CMOS 2-INPUT NOR GATE fabricated with silicon gate C2MOS technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation. This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage

The internal circuit is composed of 3 stages, including buffer output, which provide high noise immunity and stable output. All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### **FEATURES:**

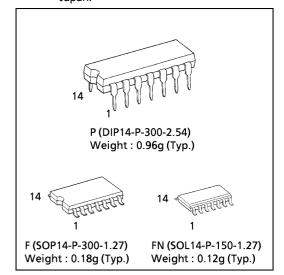
levels.

- High Speed······ $t_{pd}$  = 9ns(typ.) at  $V_{CC}$  = 5V
- Low Power Dissipation ············  $I_{CC} = 1 \mu A(Max.)$  at  $Ta = 25 ^{\circ}C$
- Compatible with TTL outputs  $\cdots V_{IH} = 2V$  (Min.)

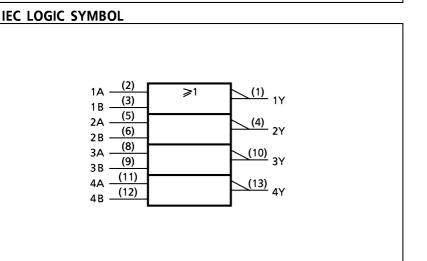
 $V_{1L} = 0.8V \text{ (Max.)}$ 

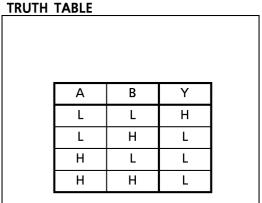
- Wide Interfacing ability ..... LSTTL, NMOS, CMOS
- Output Drive Capability ..... 10 LSTTL Loads
- Symmetrical Output Impedance | I<sub>OH</sub> | = I<sub>OL</sub> = 4mA(Min.)
- Balanced Propagation Delays  $\cdots t_{pLH} \simeq t_{pHL}$
- Pin and Function Compatible with 74LS02

(Note) The JEDEC SOP (FN) is not available in Japan.



#### **PIN ASSIGNMENT** $V_{CC}$ 1Y 14 13 4Y 1A 2 1B 3 12 4 B 2Y 4 11 4A 5 2A **3**Y 10 2B 6 3 B GND 7 3A VIEW) (TOP





# **ABSOLUTE MAXIMUM RATINGS**

DADAMETED		1/41115	
PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V <sub>cc</sub>	<b>−</b> 0.5~7	>
DC Input Voltage	V <sub>IN</sub>	$-0.5 \sim V_{CC} + 0.5$	>
DC Output Voltage	V <sub>OUT</sub>	-0.5~V <sub>CC</sub> + 0.5	<b>&gt;</b>
Input Diode Current	I <sub>IK</sub>	± 20	mA
Output Diode Current	I <sub>OK</sub>	± 20	mA
DC Output Current	I <sub>OUT</sub>	± 25	mA
DC V <sub>CC</sub> / Ground Current	I <sub>cc</sub>	± 50	mA
Power Dissipation	P <sub>D</sub>	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T <sub>stg</sub>	<b>−65~150</b>	°C

<sup>\*500</sup>mW in the range of Ta=  $-40^{\circ}\text{C}\sim65^{\circ}\text{C}$ . From Ta=65°C to 85°C a derating factor of  $-10\text{mW}/^{\circ}\text{C}$  shall be applied until 300mW.

### **RECOMMENDED OPERATING CONDITIONS**

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V <sub>cc</sub>	4.5~5.5	V
Input Voltage	V <sub>IN</sub>	0∼V <sub>cc</sub>	٧
Output Voltage	V <sub>OUT</sub>	0~V <sub>cc</sub>	V
Operating Temperature	T <sub>opr</sub>	<b>−40~85</b>	°C
Input Rise and Fall Time	t <sub>r</sub> , t <sub>f</sub>	0~500	ns

### DC ELECTRICAL CHARACTERISTICS

PARAMETER SYMBOL		. TEST CONDITION		V <sub>cc</sub>	T	Ta = 25°C		Ta = −40~85°C		UNIT
				(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
High - Level Input Voltage	V <sub>IH</sub>			4.5 \$ 5.5	2.0	_	_	2.0	_	٧
Low - Level Input Voltage	VIL			4.5 \$ 5.5	_	-	0.8	_	0.8	<b>V</b>
High - Level Output Voltage	V <sub>I N</sub> =	$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	V	
	• ОН	V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31	_	4.13	_	V
Low - Level Output Voltage	V	V <sub>IN</sub> =	$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	$\mid \ \ \mid$
	VOL	V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 4 \text{ mA}$	4.5	_	0.17	0.26	_	0.33	\ \ \ \ \
Input Leakage Current	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_	_	± 0.1	_	± 1.0	
I <sub>cc</sub>		$V_{IN} = V_{CC}$ or GND		5.5	_	_	1.0	_	10.0	$\mu$ A
Quiescent Supply Current	I <sub>C</sub>	PER INPUT:V <sub>IN</sub> OTHER INPUT	ı = 0.5V or 2.4V :V <sub>CC</sub> or GND	5.5	_	_	2.0	_	2.9	mA

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AC ELECTRICAL CHARACTERISTICS ( $C_L = 15pF$ ,  $V_{CC} = 5V$ ,  $Ta = 25^{\circ}C$ , Input  $t_r = t_f = 6ns$ )

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>		_	6	12	ns
Propagation Delay Time	t <sub>pLH</sub> t <sub>pHL</sub>		_	9	15	113

# AC ELECTRICAL CHARACTERISTICS ( $C_L = 50pF$ , Input $t_r = t_f = 6ns$ )

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT
			$V_{cc}(V)$	MIN.	TYP.	MAX.	MIN.	MAX.	CIVIII
Output Transition Time	t <sub>TLH</sub> t <sub>THL</sub>		4.5 5.5	1 1	8 7	15 13	_ _	19 16	ns
Propagation Delay Time	t <sub>pLH</sub> t <sub>pHL</sub>		4.5 5.5	1 1	12 11	18 16	_	23 20	
Input Capacitance	C <sub>IN</sub>			_	5	10	_	10	ъГ
Power Dissipation Capacitance	C <sub>PD</sub> (1)			_	18	_	_	_	pF

Note (1) C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

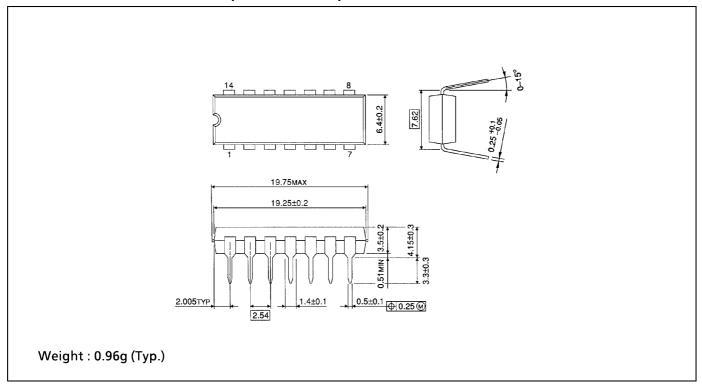
Average operating current can be obtained by the equation:

 $I_{CC}$  (opr) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4$  (per Gate)

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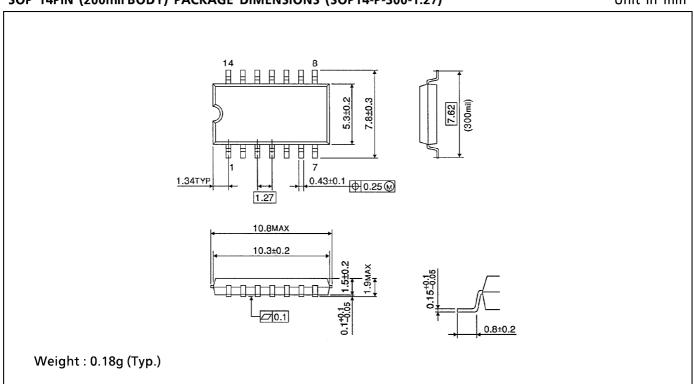
# **DIP 14PIN PACKAGE DIMENSIONS (DIP14-P-300-2.54)**

Unit in mm



# SOP 14PIN (200mil BODY) PACKAGE DIMENSIONS (SOP14-P-300-1.27)

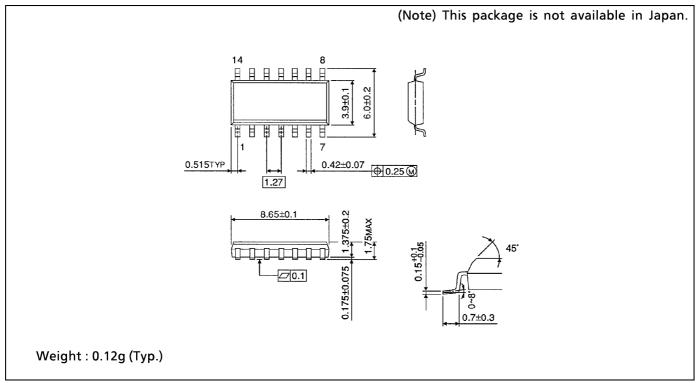
Unit in mm



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# SOP 14PIN (150mil BODY) PACKAGE DIMENSIONS (SOL14-P-150 -1.27)

Unit in mm



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